

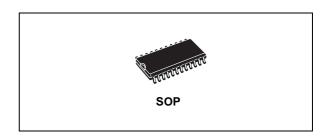
HCF4097B

ANALOG DIFFERENTIAL 8 CHANNEL MULTIPLEXER/DEMULTIPLEXER

- LOW ON RESISTANCE : 125Ω (Typ.) OVER 15V p-p SIGNAL INPUT RANGE FOR V_{DD} - V_{SS} = 15V
- HIGH OFF RESISTANCE : CHANNEL LEAKAGE OF 10pA (Typ.) at V_{DD} - V_{SS} = 10V
- MATCHED SWITCH CHARACTERISTICS : $\Delta R_{ON} = 5\Omega$ (Typ.) FOR $V_{DD} V_{SS} = 15V$
- VERY LOW QUIESCENT POWER
 DISSIPATION UNDER A DIGITAL CONTROL
 INPUT AND SUPPLY CONDITIONS: 0.2μW
 (Typ.) at V_{DD} V_{SS} = 10V
- BINARY ADDRESS DECODING ON CHIP
- QUIESCENT CURRENT SPECIFIED UP TO 20V
- STANDARDIZED SYMMETRICAL OUTPUT CHARACTERISTICS
- 5V, 10V AND 15V PARAMETRIC RATINGS
- INPUT LEAKAGE CURRENT I_I = 100nA (MAX) AT V_{DD} = 18V T_A = 25°C
- 100% TESTED FOR QUIESCENT CURRENT
- MEETS ALL REQUIREMENTS OF JEDEC JESD13B "STANDARD SPECIFICATIONS FOR DESCRIPTION OF B SERIES CMOS DEVICES"

DESCRIPTION

HCF4097B is monolithic integrated circuits fabricated in Metal Oxide Semiconductor technology available in SOP package.



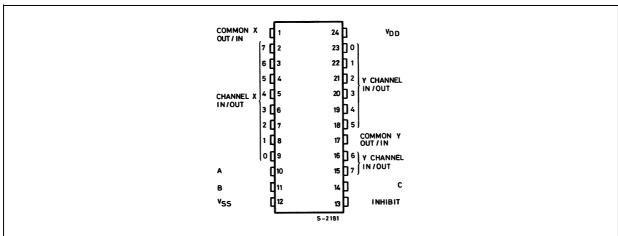
ORDER CODES

PACKAGE	TUBE	T & R
SOP	HCF4097BM1	HCF4097M013TR

HCF4097B, a analog multiplexer/demultiplexer CMOS, is a digitally controlled analog switches device having low ON impedance, low OFF leakage current and internal address decoding. in addition, the ON resistance is relatively constant over the full input-signal range.

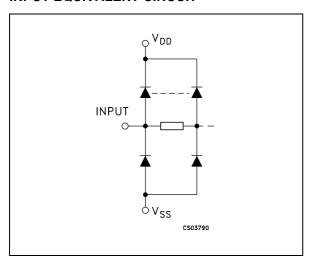
HCF4097B is a differential 8-channel multiplexer having three binary control inputs A, B, C, and an inhibit input. The inputs permit selection of one of eight pairs of switches. A logic "1" present at the inhibit input turns all channels off.

PIN CONNECTION



September 2002 1/10

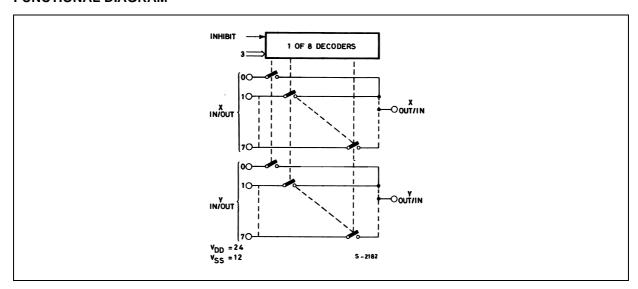
INPUT EQUIVALENT CIRCUIT



PIN DESCRIPTION

PIN No	SYMBOL	NAME AND FUNCTION
10, 11, 14	A, B, C	Binary Control Inputs
1	COMMON X OUT/IN	Common X Out/In
17	COMMON Y OUT/IN	Common Y Out/In
13	INHIBIT	Inhibit Input
9, 8, 7, 6, 5, 4, 3, 2	0 to 7 CHAN- NEL IN/OUT X	8 X channel In/Out
23, 22, 21, 20, 19, 18, 16, 15	0 to 7 CHAN- NEL IN/OUT Y	8 Y channel In/Out
12	V _{SS}	Negative Supply Voltage
24	V_{DD}	Positive Supply Voltage

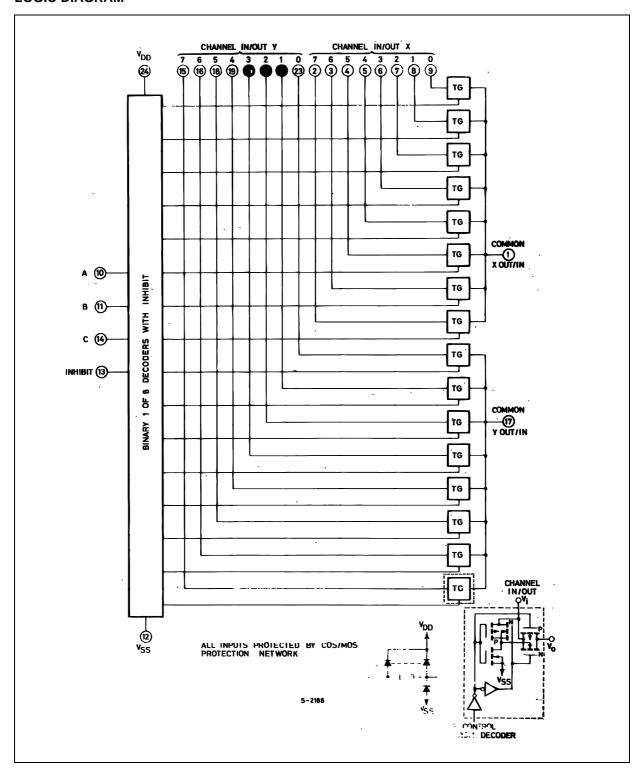
FUNCTIONAL DIAGRAM



TRUTH TABLE

Α	В	С	INH	SELECTED CHANNEL
Х	Х	X	Н	NONE
L	L	L	L	0X 0Y
Н	L	L	L	1X 1Y
L	Н	L	L	2X 2Y
Н	Н	L	L	3X 3Y
L	L	Н	L	4X 4Y
Н	L	Н	L	5X 5Y
L	Н	Н	L	6X 6Y
Н	Н	Н	L	7X 7Y

LOGIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{DD}	Supply Voltage	-0.5 to +22	V
V _I	DC Input Voltage	-0.5 to V _{DD} + 0.5	V
I _I	DC Input Current	± 10	mA
P _D	Power Dissipation per Package	200	mW
	Power Dissipation per Output Transistor	100	mW
T _{op}	Operating Temperature	-55 to +125	°C
T _{stg}	Storage Temperature	-65 to +150	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

All voltage values are referred to $V_{\mbox{\footnotesize SS}}$ pin voltage.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V_{DD}	Supply Voltage	3 to 20	V
V _I	Input Voltage	0 to V _{DD}	V
T _{op}	Operating Temperature	-55 to 125	°C

STATIC ELECTRICAL CHARACTERISTICS

 $(T_{amb} = 25^{\circ}C, Typical temperature coefficient for all V_{DD} value is 0.3 %/°C)$

		Test Condition				Value							
Symbol Parameter		V _{IS}	V _{EE}	V _{SS}		Т	T _A = 25°C		-40 to 85°C		-55 to 125°C		Unit
		(V)	(V)	(V)	(V)	Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
ΙL	Quiescent Supply				5		0.04	5		150		150	
	Current				10		0.04	10		300		300	μА
					15		0.04	20		600		600	μΑ
					20		0.08	100		3000		3000	
SWITCH								•		•		•	
R _{ON}	On Resistance	0 <u><</u> V _I			5		470	1050		1200		1200	
		V _{DD}	0	0	10		180	400		500		520	Ω
		<u> </u>			15		125	240		300		300	
Δ_{ON}	Resistance Δ_{RON}				5		10						
	(between any 2 of		0	0	10		10						Ω
	4 switches)				15		5						
OFF (•)	Channel Leakage Current Any Channel Off		0	0	18		±0.1	100		1000		1000	
	Channel Leakage Current All Channel Off (Common Out/In)		0	0	18		±0.1	100		1000		1000	μΑ
С	Capacitance Input						5						
	Output capacitance			-5	5		35						pF
	Feedthrough						0.2						
CONTRO	DL												
V_{IL}	Input Low Voltage		V _{EE} =	= V99	5			1.5		1.5		1.5	
			R _L = 11		10			3		3		3	V
		= VDD thru	- V		15			4		4		4	
V _{IH}	Input High Voltage	ιιια 1ΚΩ		uA (on	5	3.5			3.5		3.5		
				OFF	10	7			7		7		V
			chan	nels)	15	11			11		11		
I _I	Input Leakage Current	VI	= 0/18V		18		±10 ⁻³	±0.1		±1		±1	μΑ
C _I	Input Capacitance		Any Address or Inhibit Input				5	7.5					pF

The Noise Margin for both "1" and "0" level is: 1V min. with V_{DD}=5V, 2V min. with V_{DD}=10V, 2.5V min. with V_{DD}=15V
• Determined by minimum feasible leakage measurement for automating testing

$\textbf{DYNAMIC ELECTRICAL CHARACTERISTICS} \; (\textbf{T}_{amb} = 25^{\circ} \textbf{C}, \;\; \textbf{C}_{L} = 50 \text{pF}, \; \textbf{R}_{L} = 200 \text{K}\Omega, \;\; \textbf{t}_{f} = \textbf{t}_{f} = 20 \; \text{ns})$

					Test 0	Condition	on		Val	ue*	Unit
Symbol	Parameter	V _C (V)	R _L (ΚΩ)	f _I (KHz)	V _I (V)	V _{SS} (V)	V _{DD} (V)		Тур.	Max.	
SWITCH											
t _{pd}	Propagation Delay						5		30	60	
	Time (Signal Input to Output)	$= V_{DD}$	200			0	10	<u> </u>	15	30	ns
							15	V 1 O	11	20	
	Frequency Response Channel "ON" (Sine Wave							V _O at Common Out/In	20		
	Input) at $20 \text{ Log } \frac{V_O}{V_I} = -3 \text{dB}$	= V _{DD}	1		5 (•)	0	10	V _O at Any Chan- nel	60		ns
	Feedthrough (All channels OFF) at	.,	4		5 ()		40	V _O at Common Out/In	12		NALL-
	$20 \text{ Log } \frac{V_O}{V_I} = -40 \text{dB}$	= V _{SS}	1		5 (•)	0	10	V _O at Any Chan- nel	8		MHz
								Between Any two (A and B) Channels	1		MHz
	Frequency Signal Crosstalk at 20 Log VO(A) = -40dB	$V_{C(A)}$ $=V_{DD}$ $V_{C(B)}$	1		5 (•)	0	10	Between Sections (A and B) Measured on Common	10		
	V _{I(B)}	=V _{SS}						Between Sections (A and B) Measured on any Channel	18		
t _W	Sine Wave	5			2 (•)		5		0.3		
	Distortion (f _{IS} =	10	10	1	3 (•)	0	10		0.2		%
	1KHz sine wave)	15			5 (•)		15		0.12		
	(Address or Inhibit) Propagation Delay						5		325	6E0	
t _{PLH} , t _{PHL}	Time:Address or						10		135	650 270	-
	Inhibit to Signal OUT (Channel Turning ON)		1			0	15		95	190	ns
t _{PLH} , t _{PHL}	Propagation Delay						5		220	440	
	Time:Address or Inhibit to Signal OUT (Channel		0.3			0	10 15		90 65	180 130	ns
	Turning OFF) Address or Inhibit to Signal Crosstalk		10**			0	10		75		mV peak

^(*) Typical temperature coefficient for all V_{DD} value is 0.3 %/°C (**): Both Ends of Channel
(•): Peak to Peak voltage symmetrical about (V_{DD} - V_{SS}) / 2

APPLICATION INFORMATION

In applications where separate power sources are used to drive V_{DD} and the signal inputs, the V_{DD} current capability should exceed V_{DD}/R_L (R_L = effective external load). This provision avoids permanent current flow or clamp action on the V_{DD} supply when power is applied or removed from the HCF4097B.

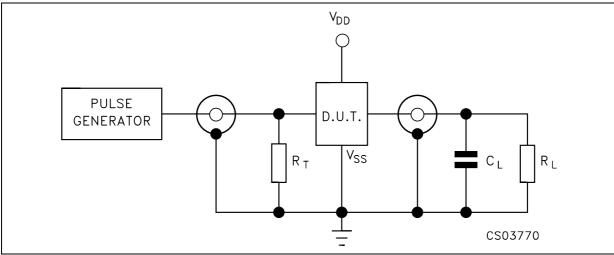
When switching from one address to another, some of the ON periods of the channels of the multiplexers will overlap momentarily, which may be objectionable in certain applications. Also, when a channel is turned ON or OFF by an address input, there is a momentary conductive path from the channel to V_{SS} , which will dump some charge from any capacitor connected to the input or output of the channel. The inhibit input turning on a channel will similarly dump some charge to V_{SS} .

The amount of charge dumped is mostly a function of the signal level above V_{SS} . Typically, at V_{DD} - V_{SS} = 10V, a 100 pF capacitor connected to

the input or output of the channel will lose 3-4% of its voltage at the moment the channel turns ON or OFF. This loss of voltage is essentially independent of the address or inhibit signal transition time, if the transition time is less than 1-2 ms. When the inhibit signal turns a channel off, there is no change dumping of $V_{\rm SS}$. Rather, there is a slight rise in the channel voltage level (65 mV typ.) due to the capacitance coupling from inhibit input to channel input or output. Address input also couple some voltage steps onto the channel signal levels.

In certain applications, the external load-resistor current may include both V_{DD} and signal line components. To avoid drawing V_{DD} current when switch current flows into the transmission gate inputs, the voltage drop across the bidirectional switch must not exceed 0.8V (calculated from R_{ON} values shown in ELECTRICAL CHARACTERISTICS CHART). No V_{DD} current will flow through R_{L} if the switch current flows into terminal 1 on the HCF4097B.

TEST CIRCUIT

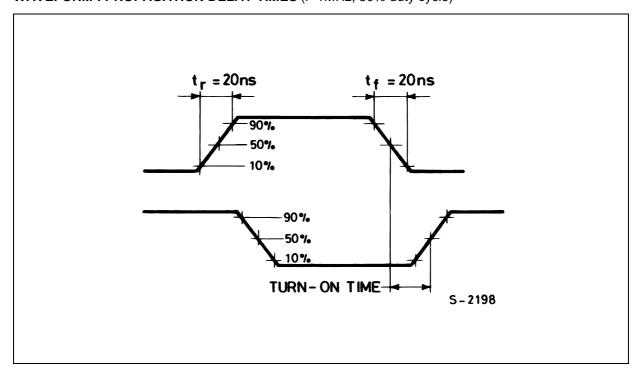


C_L = 50pF or equivalent (includes jig and probe capacitance)

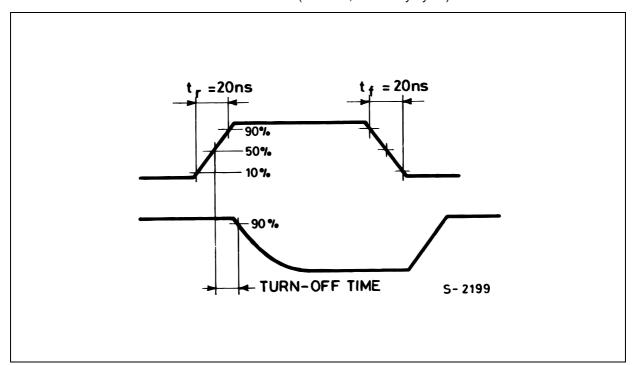
 $R_L = 200 K\Omega$

 $R_T^2 = Z_{OUT}$ of pulse generator (typically 50 Ω)

WAVEFORM: PROPAGATION DELAY TIMES (f=1MHz; 50% duty cycle)

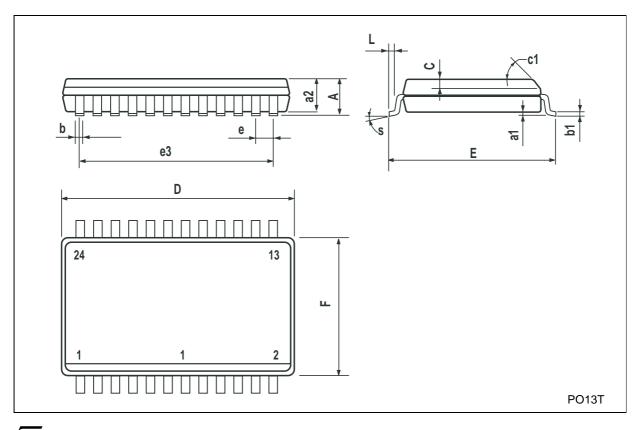


WAVEFORM: PROPAGATION DELAY TIMES (f=1MHz; 50% duty cycle)



SO-24 MECHANICAL DATA

DIM		mm.			inch						
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.					
А			2.65			0.104					
a1	0.1		0.2	0.004		0.008					
a2			2.45			0.096					
b	0.35		0.49	0.014		0.019					
b1	0.23		0.32	0.009		0.012					
С		0.5			0.020						
c1			45°	(typ.)		•					
D	15.20		15.60	0.598		0.614					
E	10.00		10.65	0.393		0.419					
е		1.27			0.050						
e3		13.97			0.550						
F	7.40		7.60	0.291		0.300					
L	0.50		1.27	0.020		0.050					
S		8° (max.)									



Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

© The ST logo is a registered trademark of STMicroelectronics

© 2002 STMicroelectronics - Printed in Italy - All Rights Reserved STMicroelectronics GROUP OF COMPANIES

Australia - Brazil - Canada - China - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco Singapore - Spain - Sweden - Switzerland - United Kingdom - United States.

© http://www.st.com